

80V +175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max Tc = +25°C	
80V	2.9mΩ @ V <sub>GS</sub> = 10V	165A	
807	5.3mΩ @ V <sub>GS</sub> = 6V	133A	

# Features

- 100% Unclamped Inductive Switching (UIS) Test in Production Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low RDS(ON) Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH83M2SPSWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

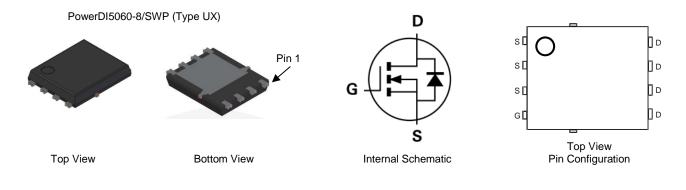
### **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Engine management systems
- Body control electronics
- DC-DC converters

#### **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



#### Ordering Information (Note 4)

Part Number	Packago	Packing		
Fait Nulliber	Package	Qty.	Carrier	
DMTH83M2SPSWQ-13	PowerDI5060-8/SWP (Type UX)	2,500	Tape & Reel	

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



## **Marking Information**



# Maximum Ratings ( $@T_C = +25^{\circ}C$ , unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		V <sub>DSS</sub>	80	V	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V	
	Tc = +25°C		165	٨	
Continuous Drain Current, V <sub>GS</sub> = 10V (Notes 5)	$T_{C} = +100^{\circ}C$	ID	117	A	
Maximum Continuous Body Diode Forward Current (Note 5)		ls	165	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		Ідм	660	A	
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle =	lsм	660	A		
Avalanche Current, L = 3mH	las	28.6	A		
Avalanche Energy, L = 3mH		E <sub>AS</sub>	1227	mJ	

## Thermal Characteristics (@T<sub>c</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	T <sub>A</sub> = +25°C	PD	4.1	W
Thermal Resistance, Junction to Ambient (Note 6)		Reja	37	°C/W
Total Power Dissipation (Note 5)	$T_{\rm C}$ = +25°C	PD	150	W
Thermal Resistance, Junction to Case (Note 5)		Rejc	1	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Thermal resistance from junction to soldering point (on the exposed drain pad).

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.



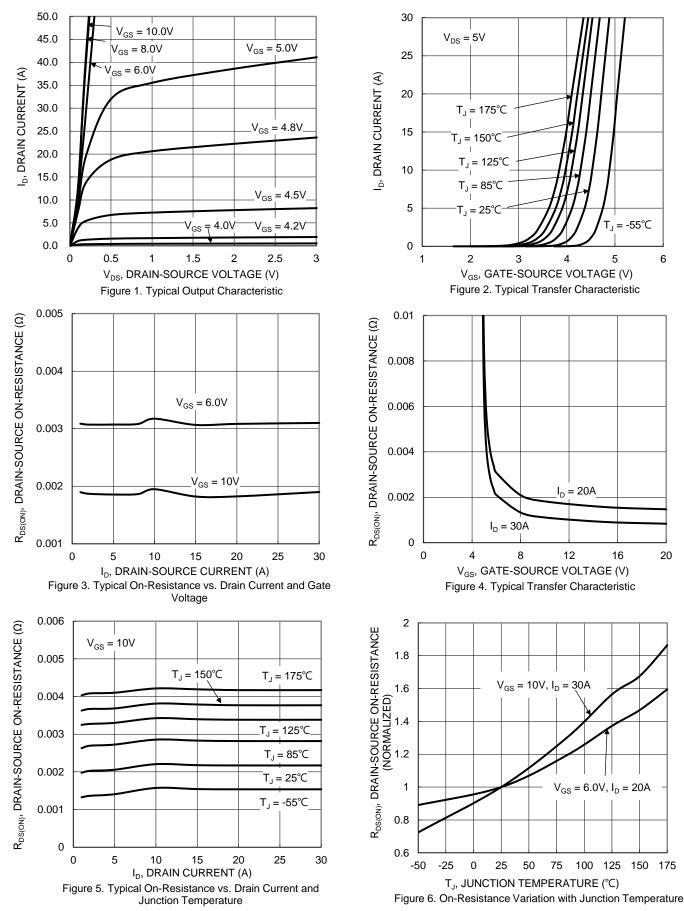
## Electrical Characteristics (@T<sub>C</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	Symbol	IVIIII	Тур	WIAX	Onit	Test condition	
Drain-Source Breakdown Voltage	BVDSS	80	_	_	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS			1	μÂ	$V_{DS} = 64V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)	1655			1100	10.0	193 - 2201, 193 - 01	
Gate Threshold Voltage	Vgs(th)	2	_	4	V	VDS = VGS, ID = 250µA	
-	. ,		2.1	2.9	mΩ	$V_{GS} = 10V, I_D = 30A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	3.5	5.3	mΩ	$V_{GS} = 6V, I_D = 20A$	
Diode Forward Voltage	Vsd	_	0.8	1.2	V	VGS = 0V, IS = 20A	
DYNAMIC CHARACTERISTICS (Note 8)				•	•	•	
Input Capacitance	Ciss		5466	_	pF	$V_{DS} = 40V, V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss		1911				
Reverse Transfer Capacitance	Crss	_	124	_			
Gate Resistance	Rg	_	1.2	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	_	87	_		V <sub>DS</sub> = 40V, I <sub>D</sub> = 30A V <sub>GS</sub> = 10V	
Gate-Source Charge	Qgs	_	27	—	nC		
Gate-Drain Charge	Q <sub>gd</sub>	_	24	—		VGS = 10V	
Turn-On Delay Time	t <sub>D(ON)</sub>	—	15	—		$V_{DD} = 40V, V_{GS} = 10V$ $I_D = 30A, R_g = 3\Omega$	
Turn-On Rise Time	tR	_	50	—	ns		
Turn-Off Delay Time	tD(OFF)	_	57	—			
Turn-Off Fall Time	tF	_	43	—			
Body Diode Reverse Recovery Time	t <sub>RR</sub>	_	72	—	ns	IF = 30A, dl/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Qrr	—	157	—	nC	$IF = 30A$ , $ul/ul = 100A/\mu S$	

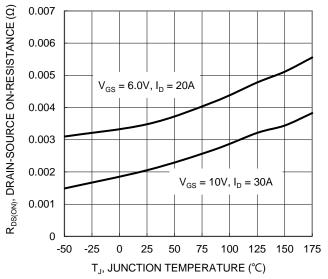
 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:



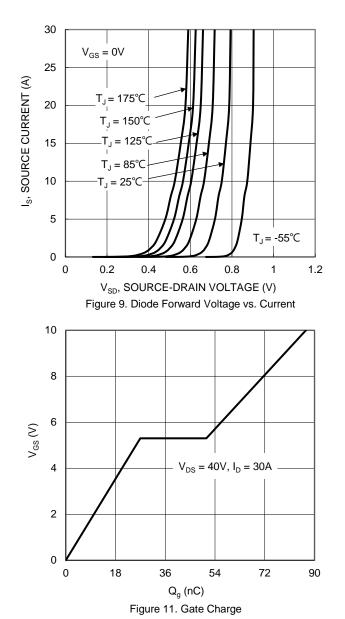
#### DMTH83M2SPSWQ

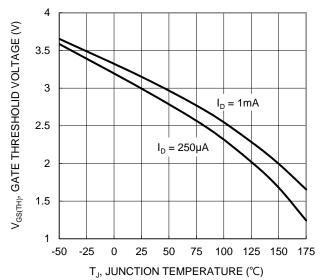




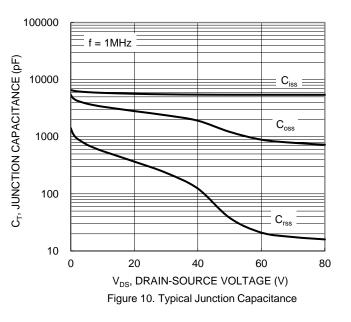


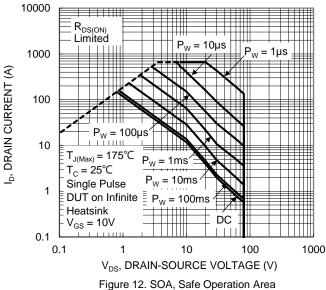








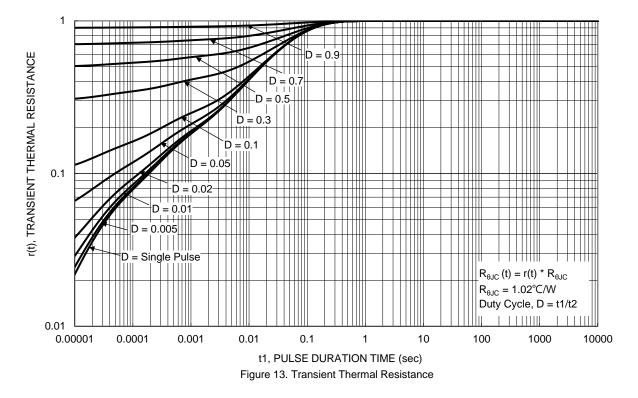




DMTH83M2SPSWQ Document number: DS45192 Rev. 3 - 2

#### DMTH83M2SPSWQ







PowerDI5060-8/SWP

(Type UX)

Max

1.10

0.05

0.50

0.35

0.25REF 0.230 0.330 0.277

5.15 BS

5.10

3.96

4.18

6.40 BS

3.86

4.595 1.27BSC

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0.050REF

4.005

12°

8

5.60 6.00

0.635 0.835

0.635 0.835

0.200 0.400

0.025 0.225

All Dimensions in mm

Тур

1.00

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0.41

0.25

4.90

3.76

3.98

5.80

3.66

4.395

0.735

0.735

0.300

0.125

3.605

11°

7

Min

0.90

0

0.30

0.20

4.70

3.56

3.78

3.46

4.195

1.05

3.205

10°

6

Dim

Α

A1

b

b2

b4

С

D

D1

D2

D2a

Е

E1

E2

E2a

е

k

L

La

L1

L1a

L4

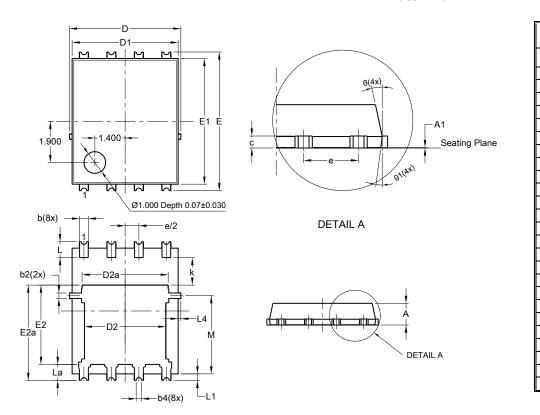
Μ

θ

θ1

#### **Package Outline Dimensions**

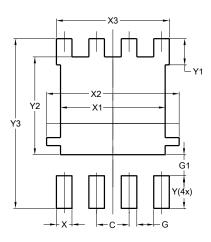
Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI5060-8/SWP (Type UX)

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**Suggested Pad Layout** 



Dimensions	Value				
Dimensions	(in mm)				
С	1.270				
G	0.660				
G1	0.820				
Х	0.610				
X1	4.100				
X2	5.190				
X3	4.420				
Y	1.270				
Y1	1.020				
Y2	3.810				
Y3	6.610				

PowerDI5060-8/SWP (Type UX)



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